NSN 5961-01-047-6726

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-047-6726 **Inclosure Material:** Metal **Overall Length:** 0.325 inches **Overall Height:** Between 0.325 inches and 0.460 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact-darlington connected **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.667 inches and 0.687 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 breakdown voltage, collector-to-base, emitter open and 175.0 breakdown voltage, collector-to-emitter, base open and 7.5 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 25.00 amperes source cutoff current **Power Rating Per Characteristic:** 100.0 watts small-signal input power, common-collector preset **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 09150-3137911 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure:**

Fiig: A110a0

No

Demilitarization: